Am27S07

64-Bit Noninverting-Output Bipolar RAM

DISTINCTIVE CHARACTERISTICS

- Fully decoded 16-word x 4-bit low power Schottky RAMs
- Internal ECL circuitry for optimum speed/power performance over voltage and temperature
- Output preconditioned during write to eliminate the write recovery glitch
- Available with three-state outputs (Am27S07)
- Electrically tested and optically inspected die for the assemblers of hybrid products

GENERAL DESCRIPTION

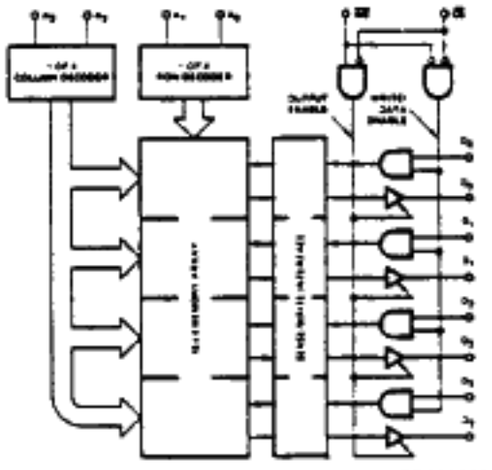
The Am27S07 is a 64-bit RAM built using Schottky diode clamped transistors in conjunction with internal ECL circuitry and is ideal for use in scratch pad and high-speed buffer memory applications. Each memory is organized as a fully decoded 16-word memory of 4 bits per word. Easy memory expansion is provided by an active LOW chip select ($\overline{CS}$) input and three-state outputs.

An active LOW Write line ($\overline{WE}$) controls the writing/reading operation of the memory. When the chip select and write lines are LOW the information on the four data inputs D_0 to D_3 is written into the addressed memory word and preconditions the output circuitry so that correct data is present at the outputs when the write cycle is complete. This preconditioning operation insures minimum write recovery times by eliminating the "write recovery glitch."

Reading is performed with the chip select line LOW and the write line HIGH. The information stored in the addressed word is read out on the four noninverting outputs O_0 to O_3.

During the writing operation or when the chip select line is HIGH the four outputs of the memory go to an inactive high impedance state.

BLOCK DIAGRAM



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MODE SELECT TABLE

Input		Data Output Status O_{0-3}	Mode
$\overline{CS}$	$\overline{WE}$		
L	L	Output Disabled	Write
L	H	Selected Word	Read
H	X	Output Disabled	Deselect

H = HIGH
L = LOW
X = Don't Care

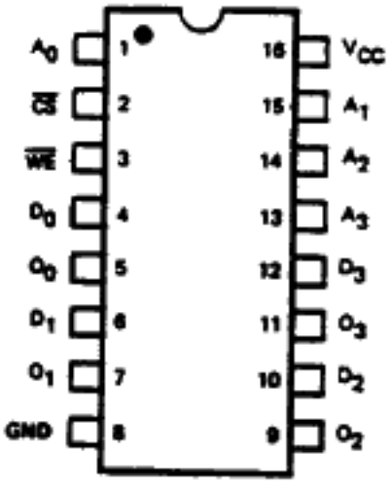
PRODUCT SELECTOR GUIDE

Access Time	25 ns	30 ns	35 ns	50 ns
I_{CC}	70 mA	70 mA	70 mA	70 mA
Temperature Range	C	M	C	M
Three-State Part Number	27S07A		27S07	

Publication # 03205 | Rev. F | Amendment /0
Issue Date: February 1989

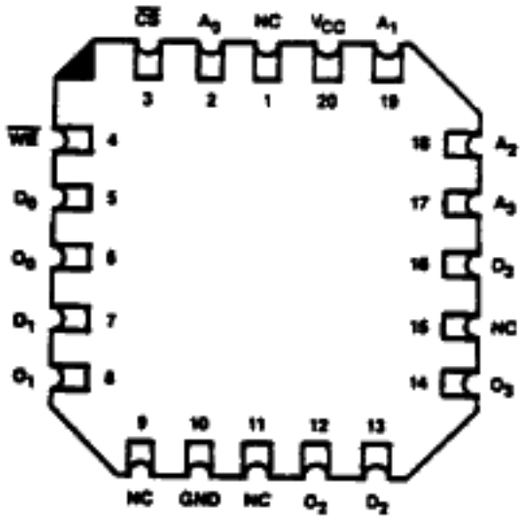
CONNECTION DIAGRAMS
Top View

DIPs*



CD000870

LCC



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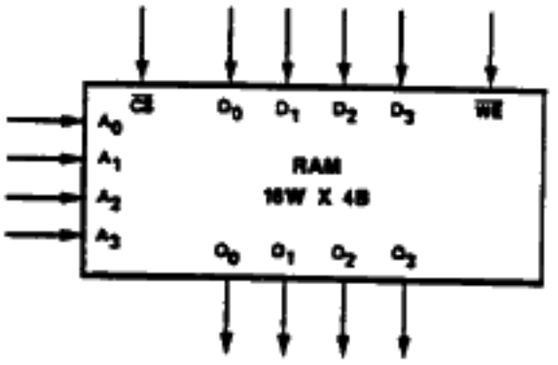
*Also available in 16-Pin Flatpack. Connections identical to DIPs.

Note: Pin 1 is marked for orientation.

LOGIC SYMBOL



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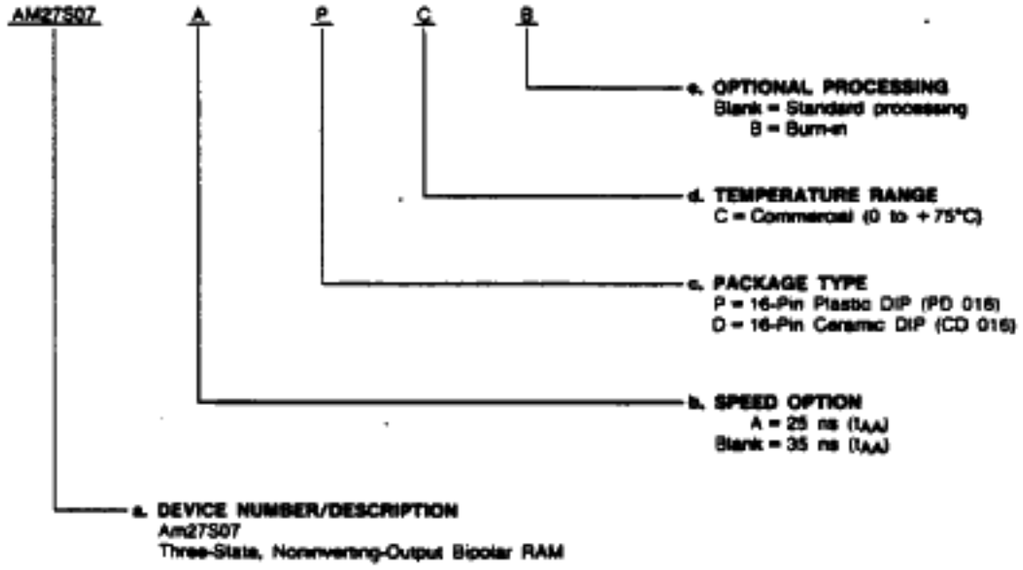
ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: **a. Device Number**
b. Speed Option (if applicable)
c. Package Type
d. Temperature Range
e. Optional Processing



Valid Combinations	
AM27S07	PC, PCB, DC, DCB
AM27S07A	

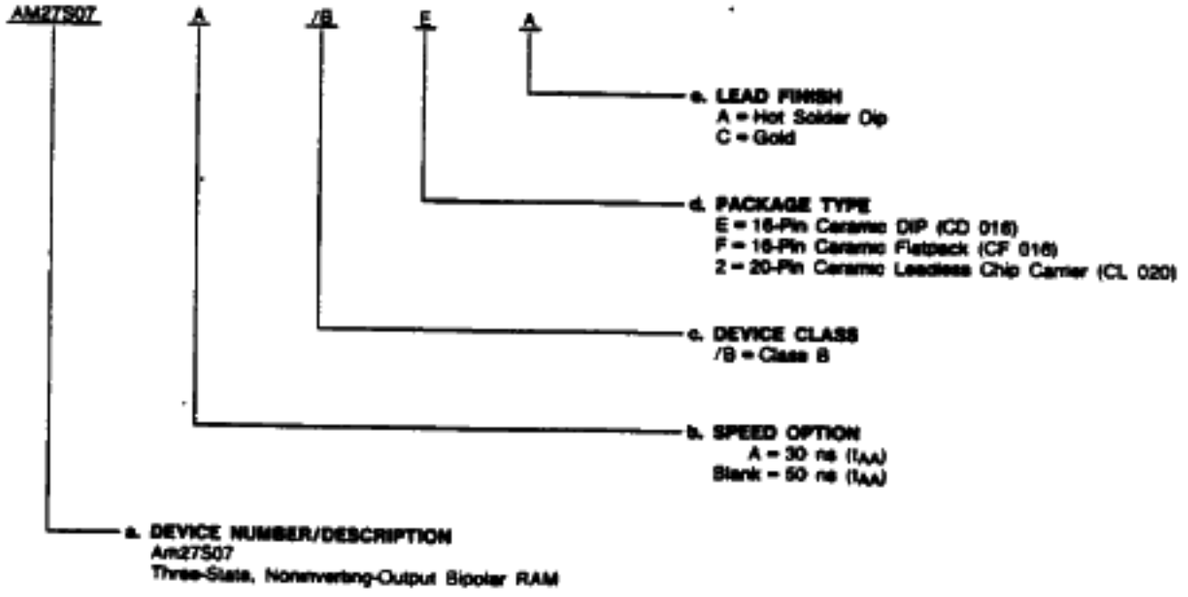
Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: **a. Device Number**
b. Speed Option (if applicable)
c. Device Class
d. Package Type
e. Lead Finish



Valid Combinations	
AM27S07	/BEA, /BFA, /B2A
AM27S07A	

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups
1, 2, 3, 9, 10, 11.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature ..... −65 to +150°C
Ambient Temperature with
Power Applied ..... −55 to +125°C
Supply Voltage ..... −0.5 V to +7.0 V
DC Voltage Applied to Outputs ..... −0.5 V to +V_{CC} Max.
DC Input Voltage ..... −0.5 V to +5.5 V
Output Current into Outputs ..... 20 mA
DC Input Current ..... −30 mA to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices
Temperature ..... 0 to +75°C
Supply Voltage ..... +4.75 V to +5.25 V

Military* (M) Devices
Temperature ..... −55 to +125°C
Supply Voltage ..... +4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

(See Note 5)

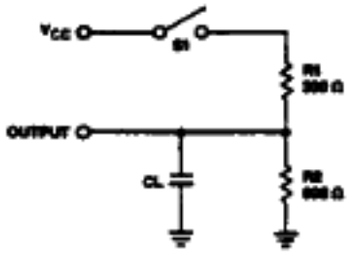
*Military Product 100% tested at T_C = +25°C, +125°C, and −55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test Conditions			Am27S07 Min.	Am27S07 Typ.	Am27S07 Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min., V_{IN} = V_{IH} or V_{IL}	I_{OH} = −5.2 mA	COM'L	2.4	3.2		V
			I_{OH} = −2.0 mA	MIL				
V_{OL}	Output LOW Voltage	V_{CC} = Min., V_{IN} = V_{IH} or V_{IL}	I_{OL} = 16 mA			350	450	mV
			I_{OL} = 20 mA			380	500	
V_{IH}	Input HIGH Level	Guaranteed Input Logical HIGH Voltage for All Inputs (Note 2)			2.0			V
V_{IL}	Input LOW Level	Guaranteed Input Logical LOW Voltage for All Inputs (Note 2)					0.8	V
I_{IL}	Input LOW Current	V_{CC} = Max., V_{IN} = 0.40 V	$\overline{WE}$, D_0–D_3, A_0–A_3			−15	−250	μA
			$\overline{CS}$			−30	−250	
I_{SC} (Note 3)	Output Short Circuit Current	V_{CC} = Max., V_{OUT} = 0.0 V			−20	−45	−90	mA
I_{CC}	Power Supply Current	All Inputs = GND, Outputs = Open, V_{CC} = Max.				50	70	mA
V_{CL}	Input Clamp Voltage	V_{CC} = Min., I_{IN} = −18 mA				−0.85	−1.2	V
I_{CEX}	Output Leakage Current	$\overline{CS}$ = V_{IH} or $\overline{WE}$ = V_{IL}, V_{OUT} = 2.4 V, V_{CC} = Max.				0	40	μA
		$\overline{CS}$ = V_{IH} or $\overline{WE}$ = V_{IL}, V_{OUT} = 0.4 V, V_{CC} = Max.			−40	0		

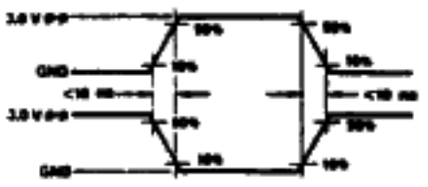
Notes: 1. Typical limits are at V_{CC} = 5.0 V and T_A = 25°C.
2. These are absolute voltages with respect to device ground pin and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
3. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.
4. Operating specification with adequate time for temperature stabilization and transverse air flow exceeding 400 linear feet per minute. Conformance testing performed instantaneously where T_A = T_C = T_J.
θ_{JA} ≈ 50°/W (with moving air) for Ceramic DIP.
θ_{JC} ≈ 10 – 17°/W for Flatpack and leadless chip carrier.

SWITCHING TEST CIRCUIT



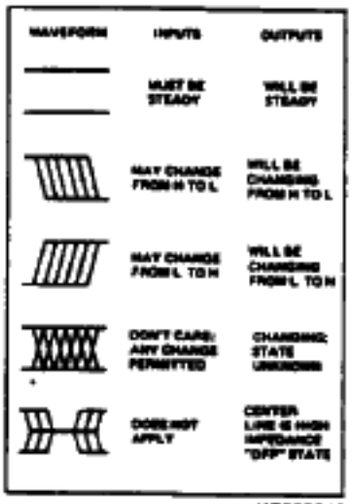
TC000201

SWITCHING TEST WAVEFORM



TW000031

KEY TO SWITCHING WAVEFORMS



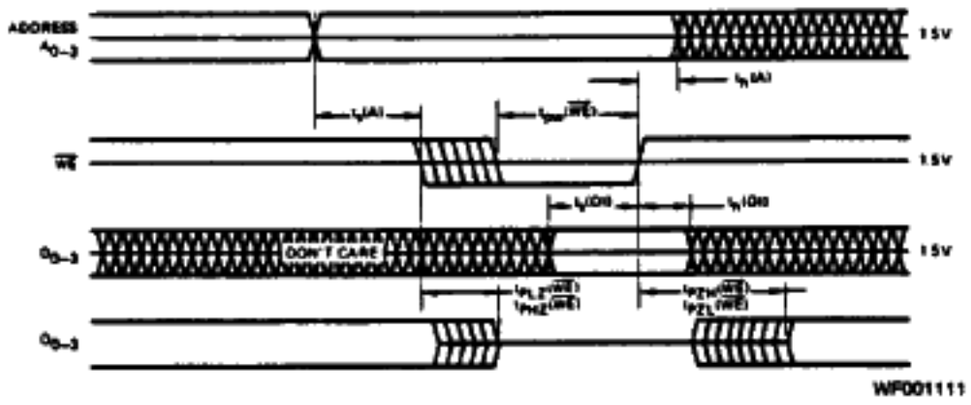
KS000010

SWITCHING CHARACTERISTICS over operating range unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted)

No.	Parameter Symbol	Parameter Description	Am27S06A/27S07A				Am27S06/27S07				Units
			C Devices		M Devices		C Devices		M Devices		
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
1	$t_{PLH}(A)$	Delay from Address to Output		25		30		35		50	ns
2	$t_{PHL}(A)$										
3	$t_{PZH}(\overline{CS})$	Delay from Chip Select (LOW) to Active Output and Correct Data		15		20		17		25	ns
4	$t_{PZL}(\overline{CS})$										
5	$t_{PZH}(\overline{WE})$	Delay from Write Enable (HIGH) to Active Output and Correct Data (Write Recovery-See Note 1)		20		25		35		40	ns
6	$t_{PZL}(\overline{WE})$										
7	$t_s(A)$	Setup Time Address (Prior to Initiation of Write)	0		0		0		0		ns
8	$t_h(A)$	Hold Time Address (After Termination of Write)	0		0		0		0		ns
9	$t_s(DI)$	Setup Time Data Input (Prior to Termination of Write)	20		25		25		25		ns
10	$t_h(DI)$	Hold Time Data Input (After Termination of Write)	0		0		0		0		ns
11	$t_{pw}(\overline{WE})$	MIN Write Enable Width Pulse to Insure Write	20		25		25		25		ns
12	$t_{PHZ}(\overline{CS})$	Delay from Chip Select (HIGH) to Inactive Output (HI-Z)		15		20		17		25	ns
13	$t_{PLZ}(\overline{CS})$										
14	$t_{PLZ}(\overline{WE})$	Delay from Write Enable (LOW) to Inactive Output (HI-Z)		20		25		25		35	ns
15	$t_{PHZ}(\overline{WE})$										

Notes:
1. Output is preconditioned to data in during write to insure correct data is present on all outputs when write is terminated. (No write recovery glitch.)
2. $t_{PLH}(A)$ and $t_{PHL}(A)$ are tested with S_1 closed and C_L = 30 pF with both input and output timing referenced to 1.5 V.
3. For 3-state output, $t_{PZH}(\overline{WE})$ and $t_{PZH}(\overline{CS})$ are measured with S_1 open, C_L = 30 pF and with both the input and output timing referenced to 1.5 V. $t_{PZL}(\overline{WE})$ and $t_{PZL}(\overline{CS})$ are measured with S_1 closed, C_L = 30 pF and with both the input and output timing referenced to 1.5 V. $t_{PHZ}(\overline{WE})$ and $t_{PHZ}(\overline{CS})$ are measured with S_1 open and $C_L \leq 5$ pF and are measured between the 1.5 V level on the input to the V_{OH} – 500 mV level on the output. $t_{PLZ}(\overline{WE})$ and $t_{PLZ}(\overline{CS})$ are measured with S_1 closed and $C_L \leq 5$ pF and are measured between the 1.5 V level on the input and the V_{OL} + 500 mV level on the output.

SWITCHING WAVEFORMS



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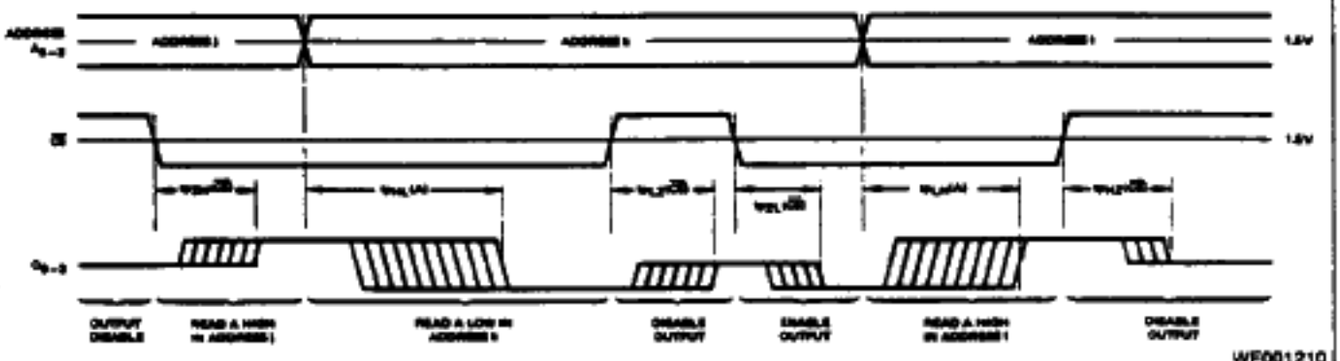
Write Mode

Write Cycle Timing. The cycle in initiated by an address change. After $t_s(A)$min, the write enable may begin. The chip select must also be LOW for writing. Following the write pulse, $t_h(A)$min must be allowed before the address may be changed again. The output will be floating for the Am27S07 while the write enable is LOW.



WF001210

Read Mode

Switching delays from address and chip select inputs to the data output. For the Am27S07 disabled output is "OFF", represented by a single center line.